

# HMC463LP5 / 463LP5E

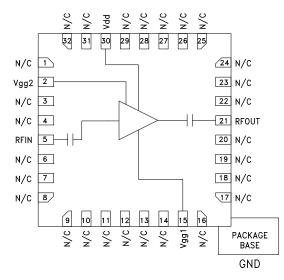
## GaAs pHEMT MMIC LOW NOISE AGC AMPLIFIER, 2 - 20 GHz

### Typical Applications

The HMC463LP5(E) is ideal for:

- Telecom Infrastructure
- Microwave Radio & VSAT
- Military EW, ECM & C3I
- Test Instrumentation
- Fiber Optics

#### **Functional Diagram**



#### Features

Gain: 13 dB Noise Figure: 2.8 dB @ 10 GHz P1dB Output Power: +18 dBm @ 10 GHz Supply Voltage: +5V @ 60mA 50 Ohm Matched Input/Output 32 Lead 5x5mm SMT Package: 25mm<sup>2</sup>

### **General Description**

The HMC463LP5(E) is a GaAs MMIC pHEMT Low Noise AGC Distributed Amplifier packaged in a leadless 5x5 mm surface mount package which operates between 2 and 20 GHz. The amplifier provides 13 dB of gain, 2.8 dB noise figure and 18 dBm of output power at 1 dB gain compression while requiring only 60mA from a +5V supply. An optional gate bias (Vgg2) is provided to allow Adjustable Gain Control (AGC) of 8 dB typical. Gain flatness is excellent at  $\pm 0.5$  dB from 6 - 18 GHz making the HMC463LP5(E) ideal for EW, ECM RADAR and test equipment applications. The HMC463LP5(E) LNA I/Os are internally matched to 50 Ohms and are internally DC blocked.

### Electrical Specifications, $T_A = +25 \text{ °C}$ , Vdd = 5V, Idd = 60 mA\*

Parameter	Min.	Тур.	Max.	Min.	Тур.	Max.	Min.	Тур.	Max.	Units
Frequency Range		2 - 6			6 - 18			18 - 20		GHz
Gain	10	13		9	12		8	11		dB
Gain Flatness		±0.5			±0.5			±0.5		dB
Gain Variation Over Temperature		0.010	0.015		0.010	0.015		0.010	0.015	dB/ °C
Noise Figure		3	4		3	5		5.5	6.5	dB
Input Return Loss		15			13			12		dB
Output Return Loss		13			10			10		dB
Output Power for 1 dB Compression (P1dB)	16	19		11	16		10	12		dBm
Saturated Output Power (Psat)		21			19			19		dBm
Output Third Order Intercept (IP3)		30			24			22		dBm
Supply Current (Idd) (Vdd = 5V, Vgg1 = -0.9V Typ.)		60	80		60	80		60	80	mA

\* Adjust Vgg1 between -2 to -0V to achieve Idd = 60 mA typical.

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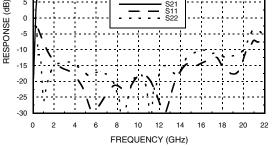
Gain & Return Loss

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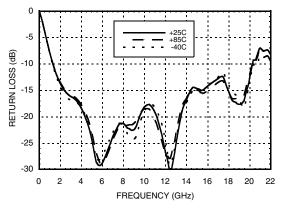
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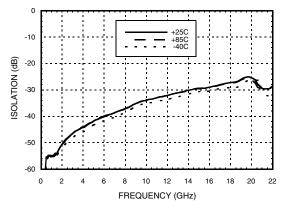
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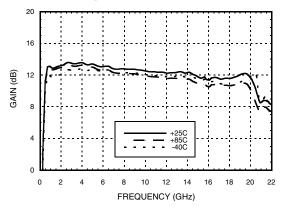
Input Return Loss vs. Temperature



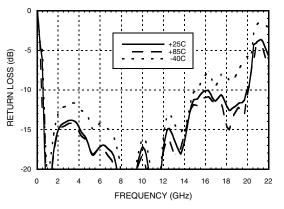
**Reverse Isolation vs. Temperature** 



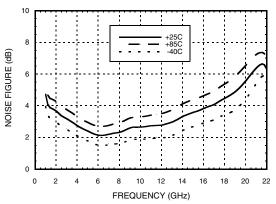
Gain vs. Temperature



Output Return Loss vs. Temperature



Noise Figure vs. Temperature



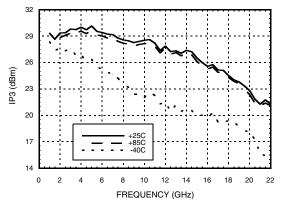


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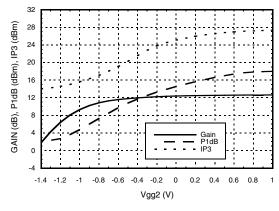
## GaAs pHEMT MMIC LOW NOISE AGC AMPLIFIER, 2 - 20 GHz

P1dB vs. Temperature 22 P1dB (dBm) 18 14 10 -850 -400 6 18 20 0 2 4 6 8 10 12 14 16 22 FREQUENCY (GHz)

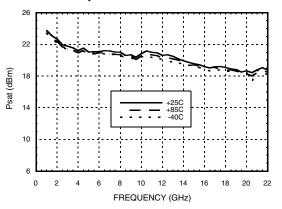
Output IP3 vs. Temperature



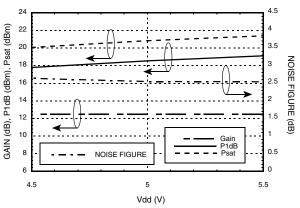
Gain, P1dB & Output IP3 vs. Control Voltage @ 10 GHz



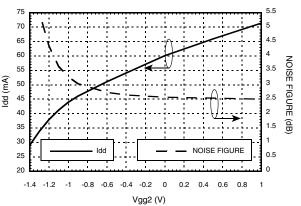
Psat vs. Temperature



Gain, Power & Noise Figure vs. Supply Voltage @ 10 GHz, Fixed Vgg1



Noise Figure & Supply Current vs. Control Voltage @ 10 GHz



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## GaAs pHEMT MMIC LOW NOISE AGC AMPLIFIER, 2 - 20 GHz

#### 13 GAIN (dB) 3 -2 -7 -12 12 16 18 20 22 0 2 8 10 14 FREQUENCY (GHz)

Gain @ Several Control Voltages (Vgg2)



#### ELECTROSTATIC SENSITIVE DEVICE OBSERVE HANDLING PRECAUTIONS

#### Absolute Maximum Ratings

Drain Bias Voltage (Vdd)	+9V		
Gate Bias Voltage (Vgg1)	-2 to 0V		
Gate Bias Current (Igg1)	2.5 mA		
Gate Bias Voltage (Vgg2)(AGC)	(Vdd -9) Vdc to +2V		
RF Input Power (RFIN)(Vdd = +5V)	+18 dBm		
Channel Temperature	150 °C		
Continuous Pdiss (T= 85 °C) (derate 19.1 mW/°C above 85 °C)	1.24 W		
Thermal Resistance (channel to ground paddle)	52.3 °C/W		
Storage Temperature	-65 to +150 °C		
Operating Temperature	-40 to +85 °C		
ESD Sensitivity (HBM)	Class 0B - Passed 150V		

## Typical Supply Current vs. Vdd

Vdd (V)	ldd (mA)		
+4.5	58		
+5.0	60		
+5.5	62		

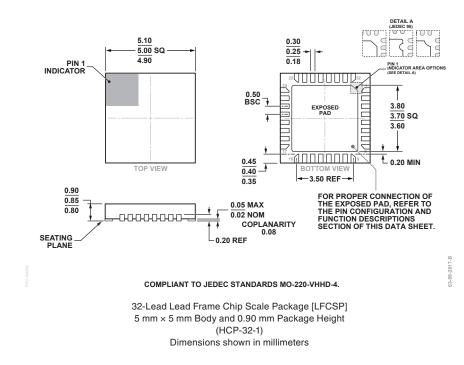


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### GaAs pHEMT MMIC LOW NOISE AGC AMPLIFIER, 2 - 20 GHz

### **Outline Drawing**



#### Package Information

Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking [3]	
HMC463LP5	Low Stress Injection Molded Plastic	Sn/Pb Solder	Solder MSL1 <sup>[1]</sup> H463 XXXX		
HMC463LP5E	RoHS-compliant Low Stress Injection Molded Plastic	100% matte Sn	MSL1 <sup>[2]</sup>	H463 XXXX	

[1] Max peak reflow temperature of 235 °C

[2] Max peak reflow temperature of 260 °C

[3] 4-Digit lot number XXXX



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## GaAs pHEMT MMIC LOW NOISE AGC AMPLIFIER, 2 - 20 GHz

### **Pin Descriptions**

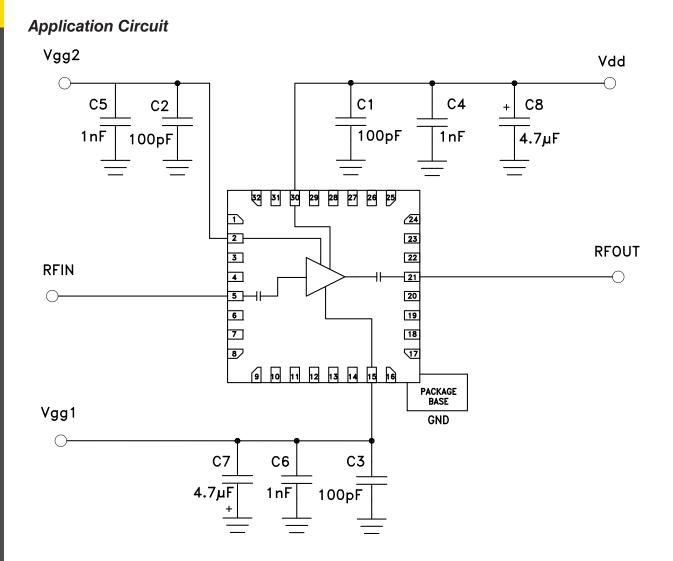
	-		
Pin Number	Function	Description	Interface Schematic
1, 3, 4, 6-14, 16-20, 22-29, 31, 32	N/C	The pins are not connected internally; however, all data shown herein was measured with these pins connected to RF/DC ground externally.	
2	Vgg2	Optional gate control if AGC is required. Leave Vgg2 open circuited if AGC is not required. Typical Vgg2 = -1.5V to 0V	Vgg2
5	RFIN	This pad is AC coupled and matched to 50 Ohms	
15	Vgg1	Gate control for amplifier. Adjust to achieve Idd = 60mA.	Vgg10
21	RFOUT	This pad is AC coupled and matched to 50 Ohms	○ RFOUT
30	Vdd	Power supply voltage for the amplifier. External bypass capacitors are required	o Vdd ↓ ↓
Ground Paddle	GND	Ground paddle must be connected to RF/DC ground.	



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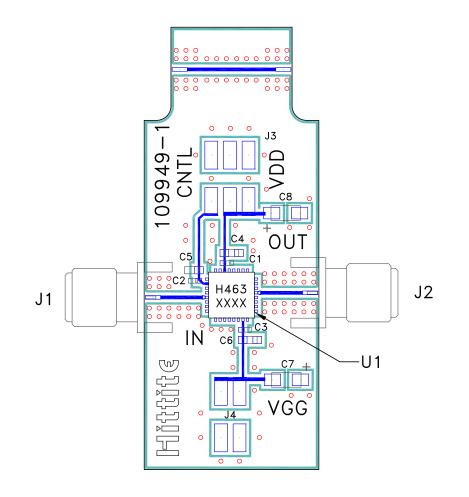
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### **Evaluation PCB**



#### List of Materials for Evaluation PCB 108341 [1]

Item	Description	
J1 - J2	SRI K Connector	
J3 - J4	2 mm Molex Header	
C1 - C3	100 pF Capacitor, 0402 Pkg.	
C4 - C6	1000 pF Capacitor, 0603 Pkg.	
C7 - C8	4.7 µF Capacitor, Tantalum	
U1	HMC463LP5(E) Amplifier	
PCB [2]	109949 Evaluation PCB	

[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Rogers 4350 or Arlon 25FR

The circuit board used in the application should use RF circuit design techniques. Signal lines should have 50 Ohm impedance while the package ground leads and package bottom should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation board should be mounted to an appropriate heat sink. The evaluation circuit board shown is available from Analog Devices upon request.

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